

LMV1015 Analog Series: Built-in Gain IC's for High Sensitivity 2-Wire Microphones

Check for Samples: [LMV1015](#)

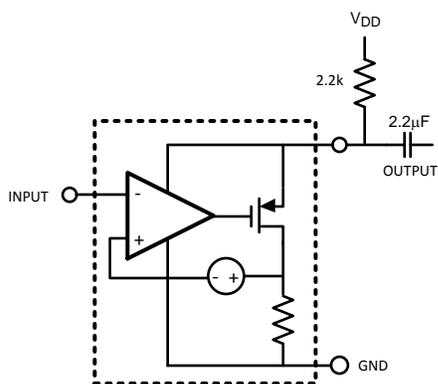
FEATURES

- (Typical LMV1015-15, 2.2V supply, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, $V_{IN} = 18\text{ mV}_{PP}$, unless otherwise specified)
- **Supply Voltage: 2V - 5V**
- **Supply Current: <180 μA**
- **Signal to Noise Ratio (A-weighted): 60 dB**
- **Output Voltage Noise (A-weighted): -89 dBV**
- **Total Harmonic Distortion 0.09%**
- **Voltage Gain**
 - LMV1015-15: 15.6 dB
 - LMV1015-25: 23.8 dB
- **Temperature Range: -40°C to 85°C**
- **Large Dome 4-Bump DSBGA Package with Improved Adhesion Technology.**

APPLICATIONS

- Cellular Phones
- Headsets
- Mobile Communications
- Automotive Accessories
- PDAs
- Accessory Microphone Products

Schematic Diagram



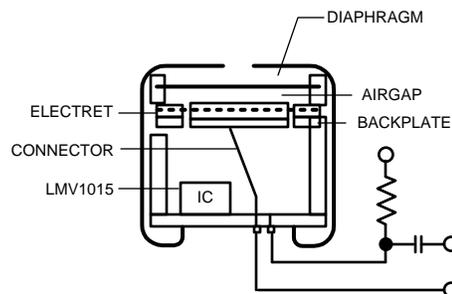
DESCRIPTION

The LMV1015 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier. The LMV1015 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1015 audio amplifiers are guaranteed to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 15.6 dB and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1015 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing older JFET market.

National Semiconductors built-in gain families are offered in extremely thin space saving 4-bump DSBGA packages (0.3 mm maximum). The LMV1015XR is designed for 1.0 mm ECM canisters and thicker. These extremely miniature packages have the Large Dome Bump (LDB) technology. This DSBGA technology is designed for microphone PCBs requiring 1 kg adhesion criteria.

Built-In Gain Electret Microphone



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

Absolute Maximum Ratings⁽¹⁾

ESD Tolerance ⁽²⁾	Human Body Model	2500V
	Machine Model	250V
Supply Voltage	V _{DD} - GND	5.5V
Storage Temperature Range		-65°C to 150°C
Junction Temperature ⁽³⁾		150°C max
Mounting Temperature	Infrared or Convection (20 sec.)	235°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.
- (2) Human Body Model (HBM) is 1.5 kΩ in series with 100 pF.
- (3) The maximum power dissipation is a function of T_{J(MAX)}, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A)/θ_{JA}. All numbers apply for packages soldered directly into a PC board.

Operating Ratings⁽¹⁾

Supply Voltage	2V to 5V
Operating Temperature Range	-40°C to 85°C
Thermal Resistance (θ _{JA})	368°C/W

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

2.2V Electrical Characteristics⁽¹⁾

Unless otherwise specified, all limits guaranteed for T_J = 25°C, V_{DD} = 2.2V, V_{IN} = 18 mV_{PP}, R_L = 2.2 kΩ and C = 2.2 μF.

Boldface limits apply at the temperature extremes.

Parameter		Test Conditions	Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units
I _{DD}	Supply Current	V _{IN} = GND	LMV1015-15	180	300 325	μA
			LMV1015-25	141	250 300	
SNR	Signal to Noise Ratio	f = 1 kHz, V _{IN} = 18 mV _{PP} , A-Weighted	LMV1015-15	60		dB
			LMV1015-25	61		
V _{IN}	Max Input Signal	f = 1 kHz and THD+N < 1%	LMV1015-15	100		mV _{PP}
			LMV1015-25	28		
V _{OUT}	Output Voltage	V _{IN} = GND	LMV1015-15	1.54 1.48	1.81 2.00	V
			LMV1015-25	1.65 1.49	1.90 2.18	
f _{LOW}	Lower -3dB Roll Off Frequency	R _{SOURCE} = 50Ω		65		Hz
f _{HIGH}	Upper -3dB Roll Off Frequency	R _{SOURCE} = 50Ω		95		kHz
e _n	Output Noise	A-Weighted	LMV1015-15	-89		dBV
			LMV1015-25	-82		
THD	Total Harmonic Distortion	f = 1 kHz, V _{IN} = 18 mV _{PP}	LMV1015-15	0.09		%
			LMV1015-25	0.15		
C _{IN}	Input Capacitance			2		pF
Z _{IN}	Input Impedance			>1000		GΩ
A _V	Gain	f = 1 kHz, R _{SOURCE} = 50Ω	LMV1015-15	14.0 13.1	15.6 17.5	dB
			LMV1015-25	22.5 21.4	23.8 25.7	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T_J = T_A. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where T_J > T_A.
- (2) All limits are specified by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

5V Electrical Characteristics⁽¹⁾

Unless otherwise specified, all limits guaranteed for $T_J = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $V_{IN} = 18\text{ mV}_{PP}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$.

Boldface limits apply at the temperature extremes.

Parameter		Test Conditions		Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units
I_{DD}	Supply Current	$V_{IN} = \text{GND}$	LMV1015-15		200	300 325	μA
			LMV1015-25		160	250 300	
SNR	Signal to Noise Ratio	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}_{PP}$, A-Weighted	LMV1015-15		60		dB
			LMV1015-25		61		
V_{IN}	Max Input Signal	$f = 1\text{ kHz}$ and $\text{THD} + \text{N} < 1\%$	LMV1015-15		100		mV_{PP}
			LMV1015-25		28		
V_{OUT}	Output Voltage	$V_{IN} = \text{GND}$	LMV1015-15	4.34 4.28	4.56	4.74 4.80	V
			LMV1015-25	4.45 4.39	4.65	4.83 4.86	
f_{LOW}	Lower -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			67		Hz
f_{HIGH}	Upper -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$			150		kHz
e_n	Output Noise	A-Weighted	LMV1015-15		-89		dBV
			LMV1015-25		-82		
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}_{PP}$	LMV1015-15		0.13		%
			LMV1015-25		0.21		
C_{IN}	Input Capacitance				2		pF
Z_{IN}	Input Impedance				>1000		$\text{G}\Omega$
A_V	Gain	$f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$	LMV1015-15	14.0 13.1	15.6	16.9 17.5	dB
			LMV1015-25	22.5 21.2	23.9	25.1 25.9	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are specified by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

Connection Diagram

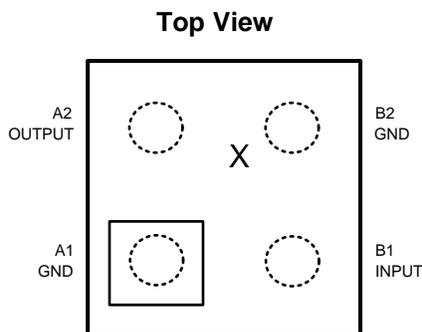


Figure 1. Large Dome 4-Bump DSBGA Package

NOTE:

- Pin numbers are referenced to package marking text orientation.
- The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

Typical Performance Characteristics

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

Supply Current vs. Supply Voltage (LMV1015-15)

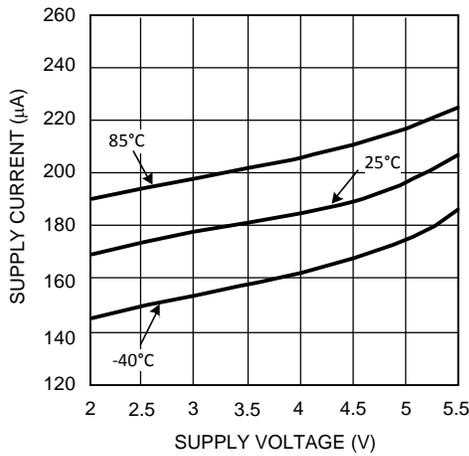


Figure 2.

Supply Current vs. Supply Voltage (LMV1015-25)

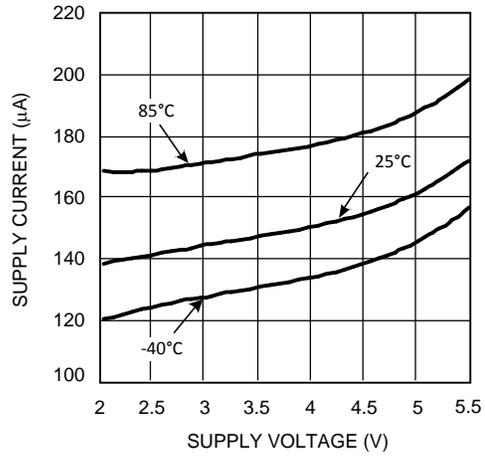


Figure 3.

Gain and Phase vs. Frequency (LMV1015-15)

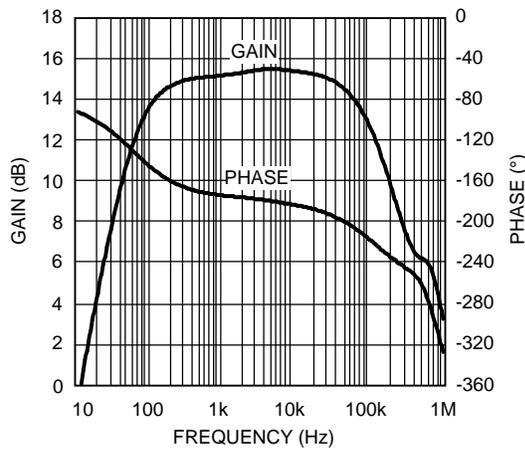


Figure 4.

Gain and Phase vs. Frequency (LMV1015-25)

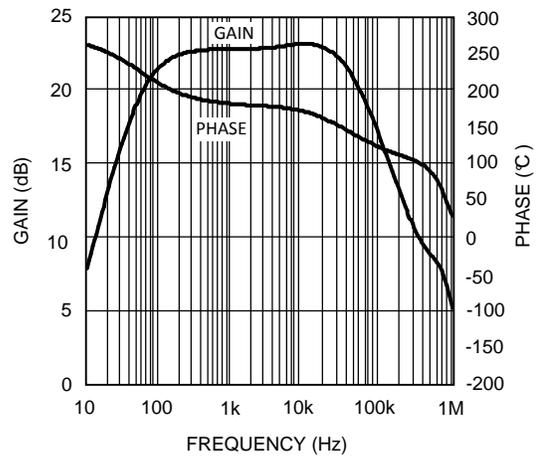


Figure 5.

Total Harmonic Distortion vs. Frequency (LMV1015-15)

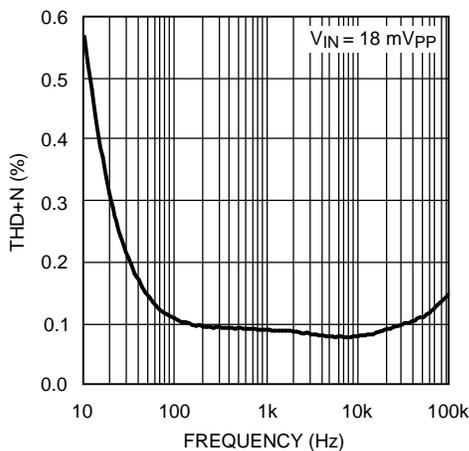


Figure 6.

Total Harmonic Distortion vs. Frequency (LMV1015-25)

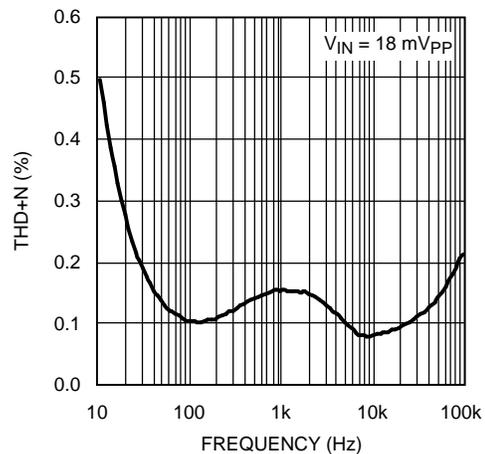


Figure 7.

Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

Total Harmonic Distortion vs. Input Voltage (LMV1015-15)

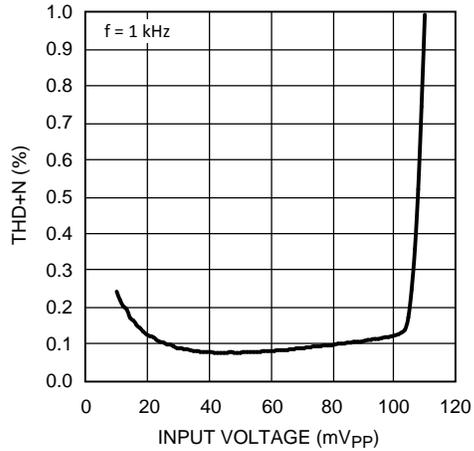


Figure 8.

Total Harmonic Distortion vs. Input Voltage (LMV1015-25)

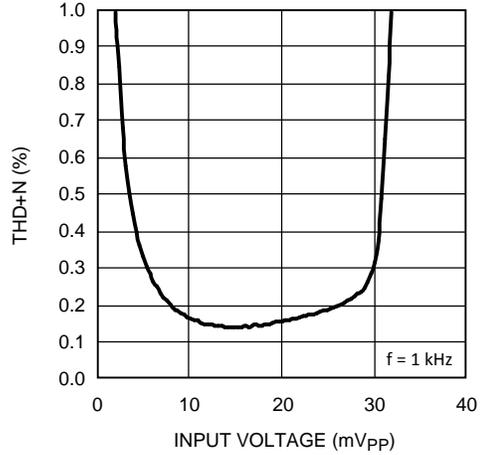


Figure 9.

Output Noise vs. Frequency (LMV1015-15)

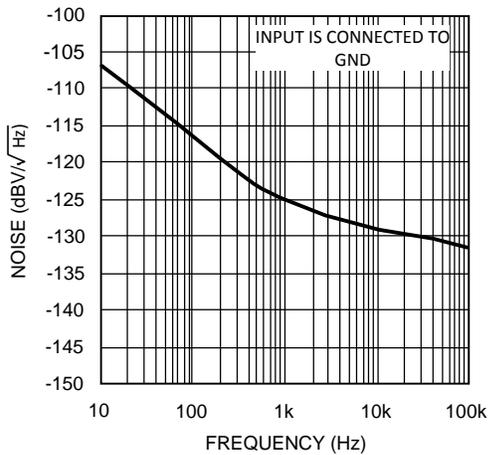


Figure 10.

Output Noise vs. Frequency (LMV1015-25)

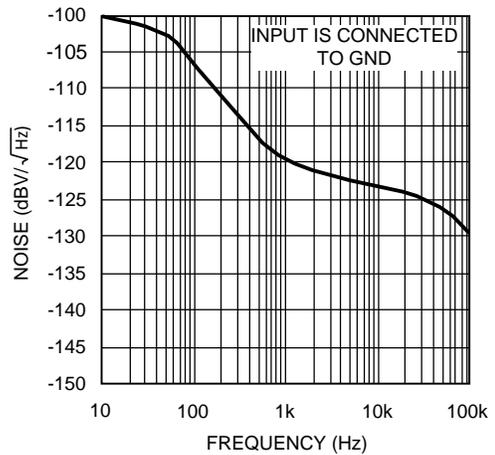


Figure 11.

APPLICATION SECTION

HIGH GAIN

The LMV1015 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1015 is offered in 0.3 mm height space saving small 4-pin DSBGA packages in order to fit inside the different size ECM canisters of a microphone. The LMV1015 is placed on the PCB inside the microphone using Large Dome Bump technology (LDB).

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.

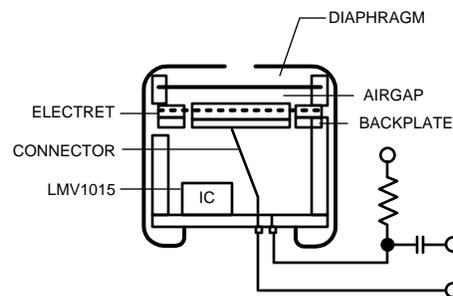


Figure 12. Built in Gain

A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.

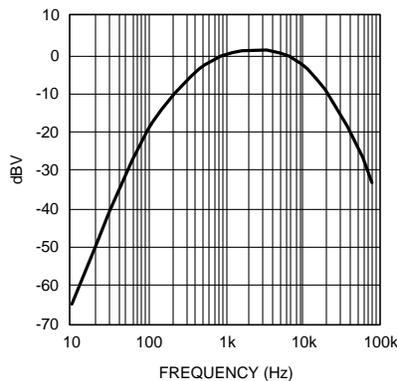


Figure 13. A-Weighted Filter

MEASURING NOISE AND SNR

The overall noise of the LMV1015 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1015 is connected to ground with a 5 pF capacitor, as in Figure 14. Special precautions in the internal structure of the LMV1015 have been taken to reduce the noise on the output.

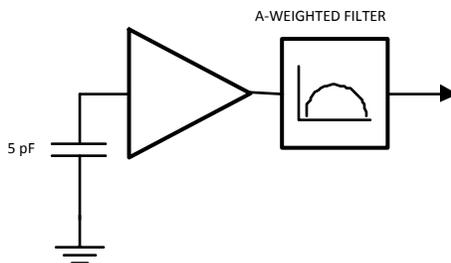


Figure 14. Noise Measurement Setup

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{pp} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

$$\text{Sound pressure level (dB)} = 20 \log P_m/P_0$$

Where,

P_m is the measured sound pressure

P_0 is the threshold of hearing (20 μ Pa)

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

$$\text{dBPa} = \text{dB SPL} + 20 \cdot \log 20 \mu\text{Pa}$$

$$\text{dBPa} = \text{dB SPL} - 94 \text{ dB}$$

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.

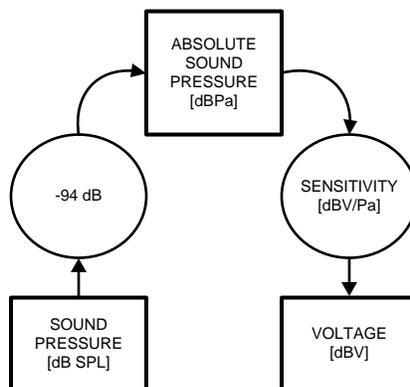


Figure 15. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL.

$$V_{OUT} = 70 - 94 - 44 = -68 \text{ dBV. This is equivalent to } 1.13 \text{ mV}_{PP}$$

Since the LMV1015-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1015-15, the sensitivity of the microphone is -28.4 dBV/Pa (-44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.

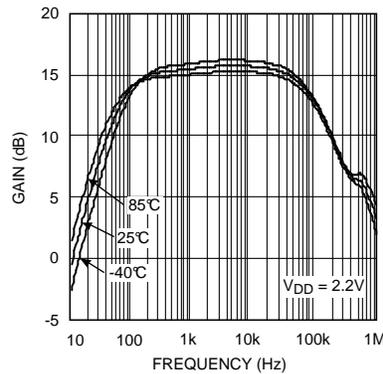


Figure 16. LMV1015-15 Gain vs. Frequency Over Temperature

The LMV1015 is optimized to be used in audio band applications. By using the LMV1015, the gain response is flat within the audio band and has linearity and temperature stability [Figure 16](#).

NOISE

Noise pick-up by a microphone in cell phones is a well-known problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 kΩ.

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AM-demodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see [Figure 17](#). One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/1900 MHz.

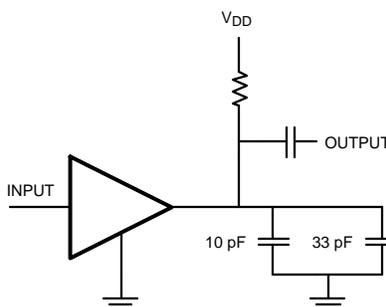


Figure 17. RF Noise Reduction

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMV1015UR-15/NOPB	ACTIVE	DSBGA	YPD	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1015UR-25/NOPB	ACTIVE	DSBGA	YPD	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1015URX-15/NOPB	ACTIVE	DSBGA	YPD	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1015URX-25/NOPB	ACTIVE	DSBGA	YPD	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1015XR-15/NOPB	ACTIVE	DSBGA	YPF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1015XR-25/NOPB	ACTIVE	DSBGA	YPF	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1015XRX-15/NOPB	ACTIVE	DSBGA	YPF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1015XRX-25/NOPB	ACTIVE	DSBGA	YPF	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

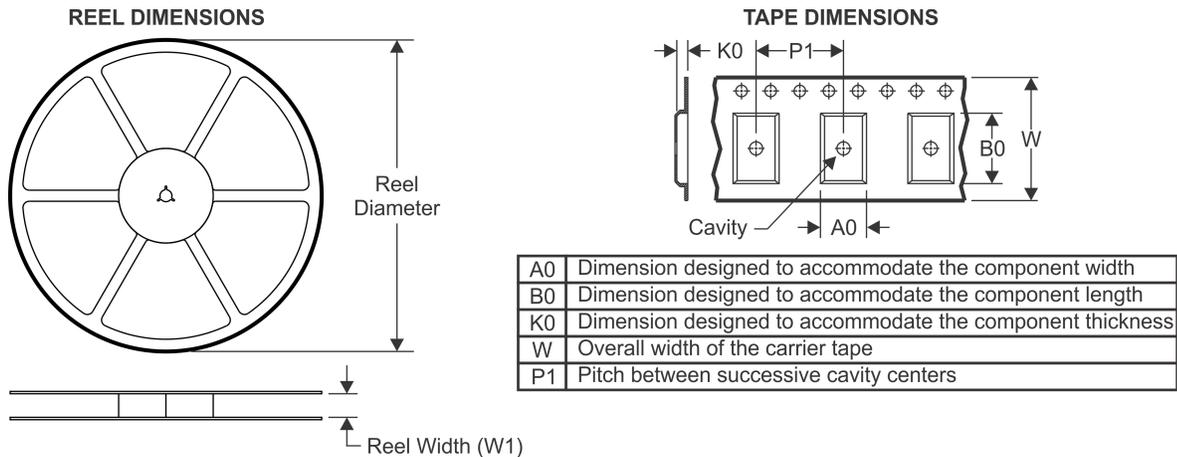
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

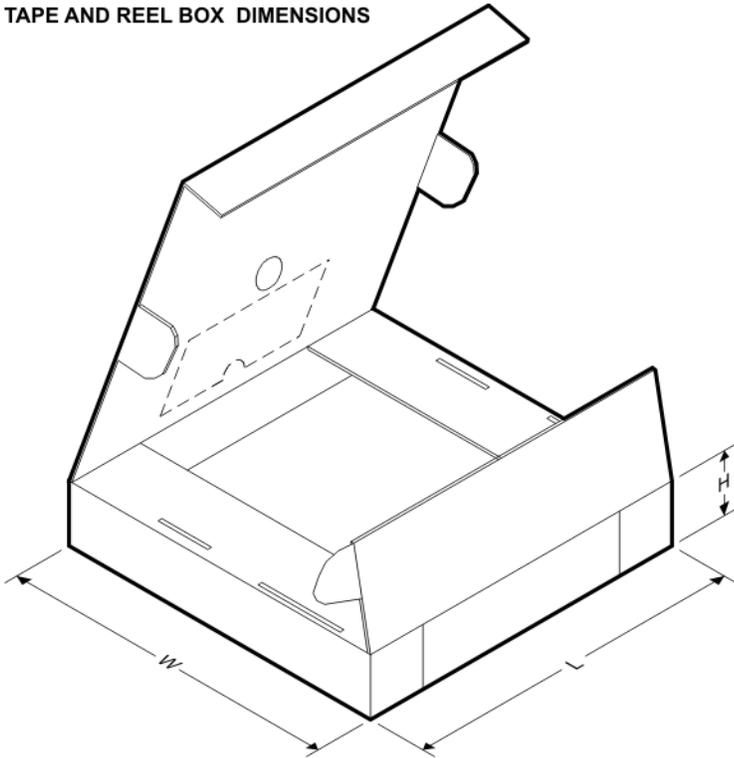
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

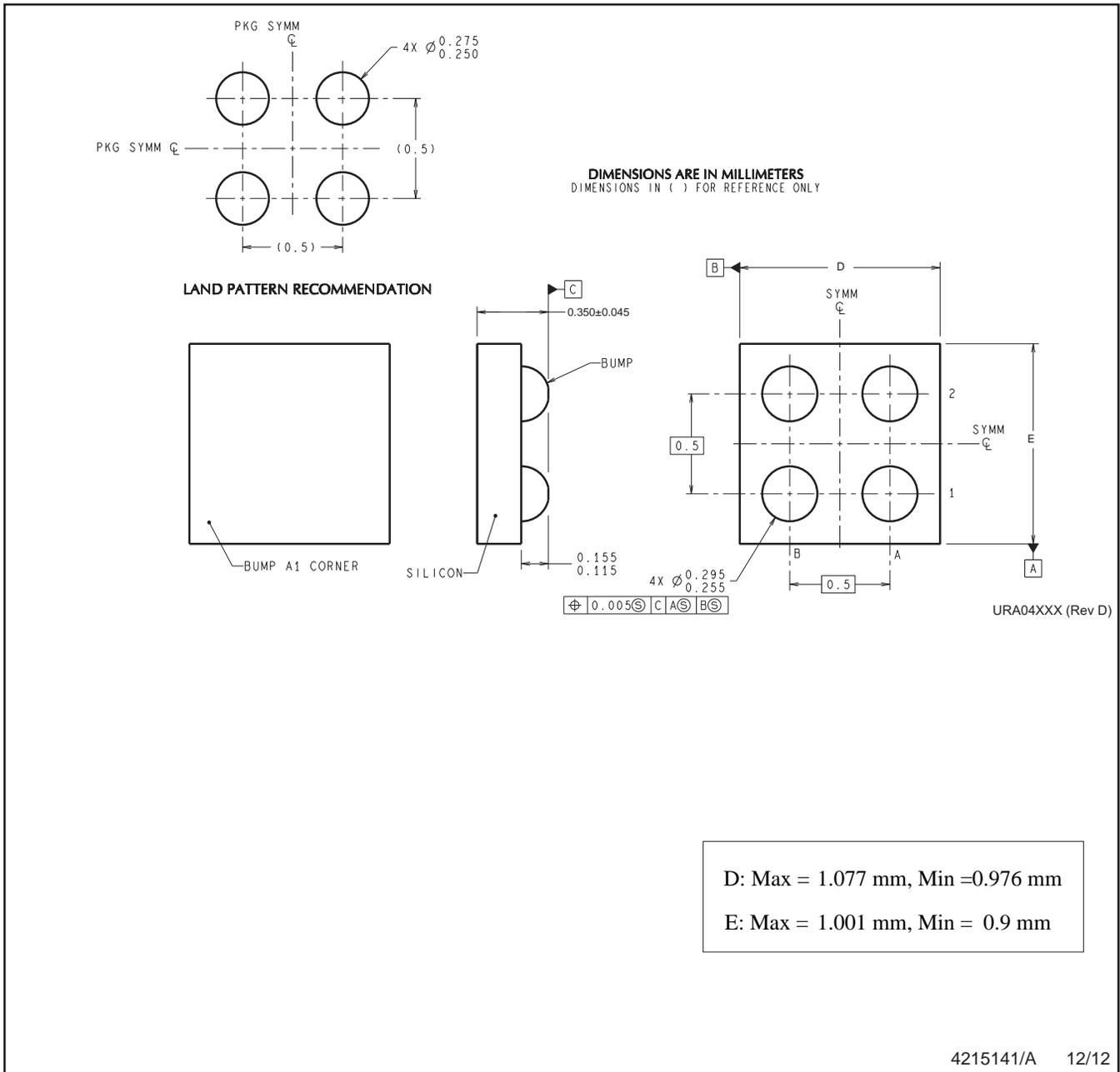
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV1015UR-15/NOPB	DSBGA	YPD	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1015UR-25/NOPB	DSBGA	YPD	4	250	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1015URX-15/NOPB	DSBGA	YPD	4	3000	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1015URX-25/NOPB	DSBGA	YPD	4	3000	178.0	8.4	1.02	1.09	0.56	4.0	8.0	Q1
LMV1015XR-15/NOPB	DSBGA	YPF	4	250	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1015XR-25/NOPB	DSBGA	YPF	4	250	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1015XR-15/NOPB	DSBGA	YPF	4	3000	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1015XR-25/NOPB	DSBGA	YPF	4	3000	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

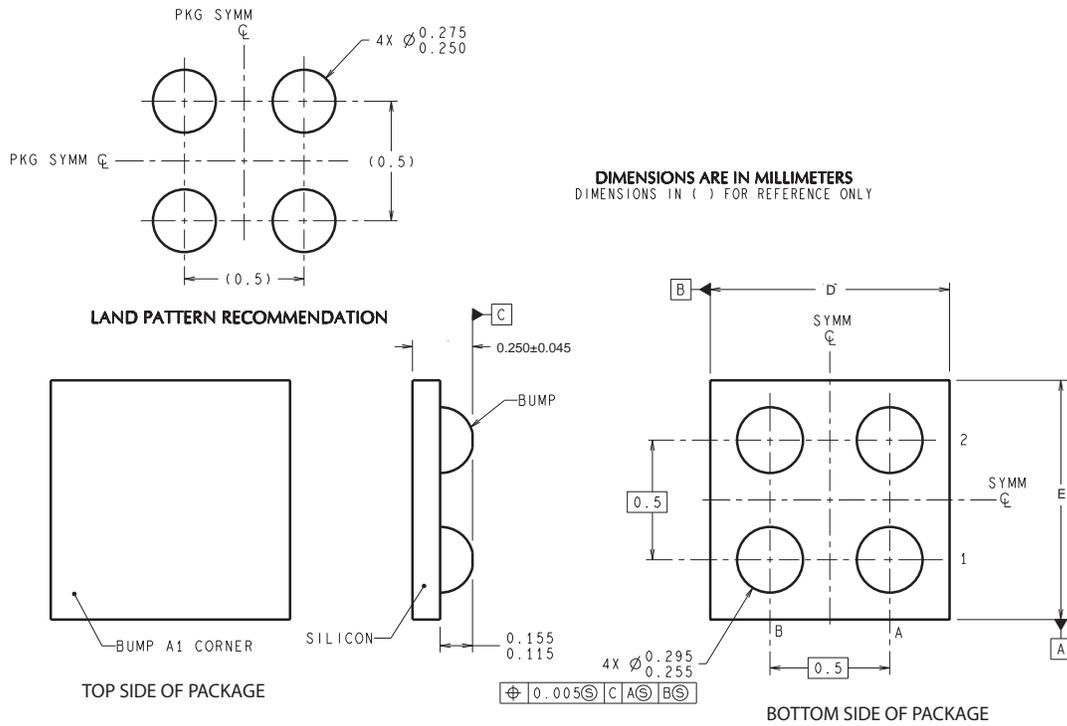
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV1015UR-15/NOPB	DSBGA	YPD	4	250	203.0	190.0	41.0
LMV1015UR-25/NOPB	DSBGA	YPD	4	250	203.0	190.0	41.0
LMV1015URX-15/NOPB	DSBGA	YPD	4	3000	206.0	191.0	90.0
LMV1015URX-25/NOPB	DSBGA	YPD	4	3000	206.0	191.0	90.0
LMV1015XR-15/NOPB	DSBGA	YPF	4	250	203.0	190.0	41.0
LMV1015XR-25/NOPB	DSBGA	YPF	4	250	203.0	190.0	41.0
LMV1015XRX-15/NOPB	DSBGA	YPF	4	3000	206.0	191.0	90.0
LMV1015XRX-25/NOPB	DSBGA	YPF	4	3000	206.0	191.0	90.0

YPD0004



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

YPF0004



XRA04XXX (Rev C)

D: Max = 1.077 mm, Min = 0.976 mm

E: Max = 1.001 mm, Min = 0.9 mm

4215204/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com